

| Item No. | Designator | Quantity | Value | Part Number | Manufacturer | Description | Packaging | Typical Dimension mm(inches) |
|-------------|-------------|----------|-------|----------------------------------|-----------------------|-----------------------|-----------------|------------------------------|
| 1 | IC1,IC2 | 2 | _ | TPD7104AF | TOSHIBA | | PS8 | 2.9 x 2.8 |
| 2 | IC3 | 1 | _ | LTC6101BCS5 | Analog Devices | | TSOT- 23 | 2.9 x 2.8 |
| 3 | Q1,Q2 | 2 | _ | TKR74F04PB | TOSHIBA | Power MOS FET | TO220- SM(W) | 10 x 13 |
| 4 | D1,D2,D3,D4 | 4 | _ | CRZ16 | TOSHIBA | Zener Diode | S-FLAT | 1.6 x 3.5 |
| 5 | D5 | 1 | _ | CMG07 | TOSHIBA | Diode | M-FLAT | 2.4 x 4.7 |
| 6 | D6,D7 | 2 | _ | CMZ27 | TOSHIBA | Zener Diode | M-FLAT | 2.4 x 4.7 |
| 7 | D8,D9,D10 | 3 | _ | 1SS352 | TOSHIBA | Diode | USC | 2.5 x 1.25 |
| 8 | R1 | 1 | 0.5mΩ | PSJ2NTEBL500F BVS-M-R0005-1.0 | KOA Isabellenhutte | 10W,±1% 9W,±1% | - | 10 x 5.2 |
| 9 | R2 | 1 | 300Ω | | | 63mW,±1% | | 1.6 x 0.8 (0603) |
| 10 | R3,R5 | 2 | 10kΩ | | | 63mW,±5% | | 1.6 x 0.8 (0603) |
| 11 | R4 | 1 | 10kΩ | | | 63mW,±1% | | 1.6 x 0.8 (0603) |
| 12 | R6,R7,R8,R9 | 4 | 10kΩ | | | 63mW,±5% | | 1.6 x 0.8 (0603) |
| 13 | R10,R11 | 2 | 20kΩ | | | 63mW,±5% | | 1.6 x 0.8 (0603) |
| 14 | R12 | 1 | 1kΩ | | | 63mW,±5% | | 1.6 x 0.8 (0603) |
| 15 | C1,C2,C3 | 3 | 1µF | | | Ceramic, 25V, ±10% | | 1.6 x 0.8 (0603) |
| 16 | C4,C5 | 2 | 10nF | | | Ceramic, 50V, ±10% | | 1.6 x 0.8 (0603) |
| 17 | C6 | 1 | 100nF | | | Ceramic, 50V, ±10% | | 1.6 x 0.8 (0603) |
| 18 | C7 | 1 | 15pF | | | Ceramic, 50V, ±5% | | 1.6 x 0.8 (0603) |



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